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Photolabile arylsilyl group: application to the oxidation of C-Si bonds

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Abstract—(2,6-Dimethoxyphenyl)-dimethylsilyl group constitutes a new orthogonal masked hydroxyl group. Protodesilylation of this arylsilane occurs under photochemical conditions in the presence of alcohols such as hexafluoroisopropanol (HFIP) or isopropanol. These mild and neutral conditions thus allowed the oxidation of organosilicon compounds such as β -hydroxysilanes that are known to be prone to Peterson elimination.

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The oxidative cleavage of carbon-silicon bonds, discovered some twenty years ago is now part of the organic chemist armory and has enjoyed a widespread interest as illustrated by numerous examples in total synthesis of natural compounds.^{1,2} The unmasking of a silicon group into the corresponding hydroxy group occurs with retention of configuration. The nature of the substituents at silicon dictates the outcome of the oxidation. Halo- and alkoxysilanes are easily oxidized using H₂O₂ in the presence of a fluorine source and such a transformation is usually compatible with many functionalities (Tamao conditions).^{1a,b} Unfortunately, such organosilanes, although readily oxidized under mild conditions are sensitive, and not compatible with long synthetic sequences. In contrast, arylsilanes such as 1 are more robust and thus stable to a wide range of reaction conditions, but in turn, their oxidation requires more drastic conditions (Scheme 1).^{1c,d,2a} Oxidation of arylsilanes is usually carried out through a two-step sequence involving a removal of the aryl group through protodesilylation, followed by peracid or H₂O₂ oxidation of the remaining activated organosilanes 2 (X = F, OR, OAc,...) (Fleming conditions). Protodesilylation which occurs under acidic conditions is usually the critical step, which may, depending on the substrate, lead to undesired by-products. Various solutions to this problem have been proposed, including the use of buffered conditions^{1d} or the design of more labile arylsilanes.^{2b,c}

The need for new generation of masked hydroxyl groups thus prompts us to report here our preliminary studies on the development of arylsilane 1 that can be converted into 2 using light under neutral conditions (ROH).

While several photocleavable OH protecting groups have been developed,³ oxidation of the C–Si bond based on a photochemical removal of a substituent at silicon (a furyl group) has been exploited only once by Kocienski et al.⁴ to carry out a critical oxidation of the C–Si bond of an allylsilane. During this oxidation, the furyl group was lost upon photooxygenation. The methodology we planned to develop is quite different since the arene at silicon would be removed through photoprotonation and thus theoretically reusable. Based on some early work by Desvergne⁵ and McClelland,⁶ it was anticipated that light-sensitive aromatic groups (Ar^{*} in 1) on the silicon center might be cleaved selectively through protodesilylation under photochemical activation in the presence of alcohols.⁷ Using photoactivation, it was



Scheme 1.

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Scheme 2.

effectively shown that alcohols such as MeOH, *t*-BuOH or hexafluoroisopropanol (HFIP) were acidic enough to protonate an arene in its singlet excited state, and at the same time nucleophilic enough to finally form the alkoxysilane intermediate **2** (Scheme 1, X = OR). The authors suggested that protodesilylation involved an associative process in which the cleavage of the C–Si bond and the formation of the Si–OR bond were concerted.

Several arenes **4a**–**d** were thus chosen as potent photolabile aryl silicon substituents (Scheme 2). Polynuclear arenes **4b**–**c** and heteroarenes **4d**–**e** were selected based on the known stability of their silicon derivatives and their UV absorption at longer wavelengths. β -hydroxysilanes were used as model compounds for our oxidation as their C–Si bond oxidation is often difficult, due to Peterson β -elimination⁸ that may occur under both acidic and basic conditions.^{2a,b}

 Table 1. Preparation of model compounds 5a-e and 6a-e (Scheme 2)

Arenes 4a-d were easily coupled through metallation with commercially available allyldimethylchlorosilane to provide the desired arylallylsilanes 5a-e in good yield (Table 1).⁹ With arene 4a, metallation then silylation occurred regioselectively between the two methoxy groups.^{9a} With dibenzofurane, mono- and bissilylation occurred (i.e., 5d-e), as reported, *ortho* to the furanyl group.^{9d} Dihydroxylation of the latter under sharpless conditions¹⁰ led to the corresponding diols 6a-e that were then protected as their acetonides 7b, 7d–e or bisacetates 7a, 7c, using standard procedures.

Irradiation of precursors 7a-e was carried out in quartz glassware using a medium pressure mercury lamp in various non degassed alcohols (distilled prior to irradiation) at room temperature under an air atmosphere. A cooling bath was generally used to maintain the temperature close to 20 °C. The product of the reaction was then simply recovered after evaporation of the solvent under reduced pressure. Preliminary experiments (Table 2, entries 1 and 2) were carried out using 7a, which upon irradiation in HFIP, unexpectedly provided disiloxane **8a** (PG = OAc) and none of the desired alkoxysilane, as indicated by ¹H NMR and mass spectrometry.¹¹ It is worthy of note that 1,3-dimethoxybenzene could also be recovered and may thus be recycled. In some cases, small amounts of silanol 9 (9a, PG = OAc) were detected, indicating that water was present in the medium.¹² Different attempts to remove water using 3 Å molecular sieves and a nitrogen atmosphere were however unsuccessful. On the contrary, addition of 10% (vol.) of water led to similar results, indicating that water likely catalyzes the formation of siloxane $8a^{13}$ through dimerization of silanol 9a (PG = OAc).

Although we were able to recover expensive HFIP through distillation, other solvents were tested as possible alternatives. Isopropanol led to encouraging results (entries 4 and 5), although the reaction was much slower than that with HFIP. Methanol led to mixtures of **8a** and starting material (entry 3) and trifluoroethanol (entry 6) led to decomposition. Under these conditions, α - and β -naphthylsilanes **7b** and **7c** led to no reaction

Entry	ArX	Conditions ^a	% Yield ^c 5a–e	% Yield ^c 6a–e
1	4a	n-BuLi (1 equiv), TMEDA	5a (84)	6a (99)
	(X = H)	Hexane, 0 °C to rt, 22 h		
2	4b	t-BuLi (2 equiv), THF	5b (75)	6b (98)
	$(\mathbf{X} = \mathbf{Br})$	−78 °C, 5 h		
3	4c	t-BuLi (2 equiv), THF	5c (99)	6c (91)
	$(\mathbf{X} = \mathbf{Br})$	-78 °C, 5 h		
4	4d	n-BuLi (1 equiv), THF	5d (77) ^d	6d (100) ^f
	(X = H)	rt, ^b 22 h		
5	4d	n-BuLi (2 equiv), THF	5e (35) ^e	6e (95) ^f
	(X = H)	rt, ^b 22 h		

^a Allyldimethylchlorosilane was added after metallation and the reaction mixture stirred for the period reported above.

^b The reaction mixture was refluxed after the addition of allyldimethylchlorosilane.

^c Isolated yields unless otherwise mentioned.

^d 11% of bissilylated product **5e** was also isolated.

^e 57% of monosilylated product **5d** was also isolated.

^fCrude yield.

Table 2. Irradiation of model compounds 7a-e

	$\begin{array}{ccc} Ar & Si & OPG \\ Me_2 & OPG \end{array} \xrightarrow{hv} & O(Si & OPG \\ Me_2 & OPG \end{array} \xrightarrow{hv} & O(Si & OPG \\ Me_2 & OPG \end{array} \xrightarrow{OPG} OPG \\ OPG \end{array}$						
	7	a-e	8	9			
Entry	Arylsilane	ROH ^a		Time (h) ^b	% Yield ^c		
1	7a	HFIP		14	8a (quant.)		
2	7a	HFIP-MeOH	(22 equiv)	44	8a (quant.)		
3	7a	MeOH		26	d		
4	7a	<i>i</i> -PrOH		25	e		
5	7a	<i>i</i> -PrOH		56	8a (quant.)		
6	7a	CF ₃ CH ₂ OH		27	decomp.		
7	7b	HFIP		48	7b (quant.)		
8	7c	HFIP (40 equi	v)–MeOH	26	7c (quant.)		
9	7d	HFIP		28	7d (quant.)		
10	7e	HFIP		28	7e (quant.)		

^a Arylsilanes **7a–e** were dissolved in the indicated solvent (C = 10-20 mmol/l) and irradiated at 20 °C using a medium pressure mercury lamp. ^b Irradiation time.

^cCrude yields after evaporation of the solvent.

^d A 56:44 mixture of 7a/8a was estimated from ¹H NMR of the crude reaction mixture.

^eA 58:42 mixture of 7a/8a was estimated from ¹H NMR of the crude reaction mixture.

and surprisingly starting materials were recovered unchanged, whatever the conditions (entries 7 and 8). Similarly, dibenzofuranylsilanes 7d and 7e were also recovered unchanged after irradiation for 28 h in HFIP (entries 9 and 10).

As water likely assists the protodesilylation⁶ to form the silanol (i.e., 9) which then dimerizes, it was decided to carry out the reaction on a precursor such as 6a, having an hydroxyl group close to silicon that could approach the silicon center to form siloxane 10 and thus prevent the nucleophilic attack by water (Scheme 3). Irradiation of 6a was thus carried out as above, but disiloxane 11 was the only product of the reaction with none of the expected cyclic siloxane 10 formed.

These results suggest that disiloxanes are the thermodynamically favored compounds due to the formation of two strong Si–O bonds. Therefore, it was decided to test the oxidation on **8a** as it is easily obtained in quantitative yield. Different conditions were thus tested that led consistently to complex mixtures of polysiloxanes. Finally, when the oxidation was conducted in the presence of acetic anhydride, 30% H₂O₂ and KF in DMF,^{1a,b} the desired alcohol **12** was obtained, albeit in modest yield (Scheme 4). The role of acetic anhydride is not clear. Siloxanes are difficult to oxidize and their





Scheme 4.

reactions under the usual Tamao conditions probably lead to siloxanes and polysiloxanes, through dimerization of silanols formed in situ. Acetic anhydride might react with the latter and thus prevent the formation of siloxanes, through the formation of acetoxysilanes which are easier to oxidize.

The study was then extended to related hydroxycarbamate 13 which is also prone to Peterson elimination. 13 was prepared from allylsilane 5a using sharpless amino-hydroxylation (AA) protocol.¹⁴ This led to a 2.5:1 mixture of regioisomers 13 and 14 (Scheme 5),



Scheme 5.

which were easily separated by chromatography.¹⁵ **13** was then irradiated as above to provide disiloxane 15^{16} in quantitative yield. Oxidation of crude **15** under the optimized conditions above led to diol $16^{15,17}$ in a satisfying 67% yield.

These results thus unambiguously show that the 2,6dimethoxyphenylsilyl group can be considered as a new potent masked hydroxyl group. It is stable under basic conditions and in mildly acidic medium.¹⁸ It is cleaved under neutral conditions which should be compatible with the presence of other arylsilyl groups. One could then envisage a selective oxidation of this aryl group in the presence of other aryldimethylsilanes such as PhMe₂Si,^{2a,b} *p*-TolMe₂Si¹⁹ or the recently developed (Ph₂CH)Me₂Si group.²⁰ Interestingly, when treated under buffered Fleming conditions^{1c,d} (AcOOH, AcO-Na, KBr, rt, 88 h), **7a** led to **12** with only 50% conversion and did not produce the desired alcohol under Tamao conditions^{1a,b} (30% H₂O₂, K₂CO₃, KF, THF– MeOH, rt, 73 h).

In summary, we devised a photolabile arylsilicon group that can be used for the C–Si bond oxidation. Protodesilylation occurs under neutral conditions, generating a siloxane that may then be oxidized under standard conditions. Our preliminary results demonstrate that the methodology is useful for the oxidation of acid and base sensitive organosilanes. Application of this sequence to more complex organosilanes is under way and will be reported in due course.

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- 11. Stirring of the organosilanes in HFIP in the absence of irradiation led to no reaction, indicating that the conjunction of alcohol and the irradiation was necessary for the protodesilylation to occur.
- 12. Alkoxysilanes may be isolated under strictly anhydrous conditions,⁶ which are not really suitable for preparative chemistry.
- 13. General procedure for photoprotonation of 2,6-dimethoxyphenylsilyl group: The solution of the arylsilane (0.3 mmol) in HFIP (14 ml) was irradiated over a period of 14 h. After evaporation of the solvent and 1,3-dimethoxybenzene, the crude siloxane was obtained as a yellow oil that was not purified further, but used directly in the next step. **8a**: ¹H NMR (300 MHz, CDCl₃): δ 5.26–5.14 (m, 1H), 4.24–4.19 (m, 1H), 3.91 (dd, J = 7.0 Hz, 11.9 Hz, 1H), 2.02 (s, 3H), 2.00 (s, 3H), 1.01–0.86 (m, 2H), 0.11 (s, 3H), 0.09 ppm (s, 3H). ¹³C NMR: (75.5 MHz, CDCl₃): δ 170.8, 70.4, 69.6, 66.9, 21.3, 20.9, 20.8, 1.4, 0.9 ppm. MS (LSIMS, FAB⁺) m/z: 235 (34%); 265 (8%); 281 (6%); 413 (10%); 473 ([M+Na]⁺, 100%).
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- 16. Compound **15**: ¹H NMR (250 MHz, CDCl₃): δ 5.38 (br s, 1H), 4.08 (quart, J = 6.8 Hz, 2H), 3.94–3.90 (m, 1H), 3.33–3.24 (m, 1H), 3.03–2.91 (m, 1H), 1.21 (t, J = 7.0 Hz, 3H), 1.06–0.71 (m, 2H), 0.26 (d, 3H), 0.18–0.05 ppm (m, 3H). ¹³C NMR: (75.5 MHz, CDCl₃): δ 157.6, 68.8, 61.1, 49.6, 24.9, 14.7, 1.6, 1.2 ppm.
- 17. General procedure for the disiloxane oxidation: To a solution of disiloxane (0.2 mmol) in DMF (2.2 ml) was added at room temperature, KF (1 mmol) and then at 0 °C acetic anhydride (1 mmol) and a 30% aqueous solution of H_2O_2 (10 mmol). The reaction mixture was stirred at 60 °C for 36 h, then quenched with a 25% Na₂S₂O₃ solution. After the addition of a 0.5% solution of HCl (5 ml), the reaction mixture was extracted with diethylether (3×) and dried over Na₂SO₄. Evaporation of the solvent in vacuo and purification of the residue by column chromatography led to the desired alcohol. *Compound* 16:¹⁵ ¹H NMR (250 MHz, CDCl₃): δ 5.56 (br s, 1H), 4.11 (quart,

J = 7.0 Hz, 2H), 3.95 (s, 1H), 3.74 (m, 2H), 3.65–3.49 (m, 2H), 3.37–3.16 (m, 2H), 1.23 ppm (t, J = 7.0 Hz, 3H). ¹³C NMR: (62.4 MHz, CDCl₃): δ 158.1, 71.4, 63.9, 61.4, 43.3, 14.7 ppm.

18. The 2,6-dimethoxyphenylsilyl group is also stable to thermal radical conditions as illustrated by the carboaz-idation of allylsilane **5a**:



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